TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC237AP, TC74HC237AF

3 – TO – 8 LINE DECODER / LATCH

The TC74HC237A is a high speed CMOS 3 - to - 8 LINE DECODER ADDRESS LATCH fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

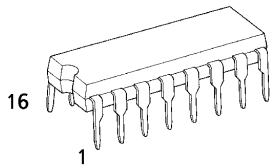
It is composed of a 3 - bit input latches with a common $\overline{GL}$ enable input and 3 - to - 8 line decoder with enable inputs G1 and $\overline{G}2$. The 3 - bit binary data is stored into the input latch on the high level of $\overline{GL}$. The value of this data determines which one of the outputs will go low.

When the enable input G1 is held low or $\overline{G}2$ is held high, decoding function is inhibited and all the 8 outputs go high. The two enable inputs are provided to ease cascade connection and permits the application address decoder for memory system.

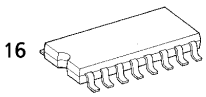
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

- High Speed ····· t_{pd} = 12ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 4μA(Max.) at Ta = 25°C
- High Noise Immunity ····· $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Output Drive Capability ····· 10 LSTTL Loads
- Symmetrical Output Impedance ··· $|I_{OH}| = I_{OL}$ = 4mA(Min.)
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr.) = 2V ~ 6V
- Pin and Function Compatible with 74LS237

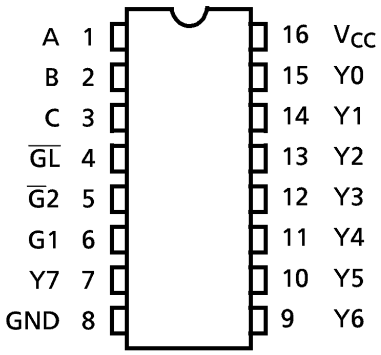


P (DIP16-P-300-2.54A)
Weight : 1.00g (Typ.)



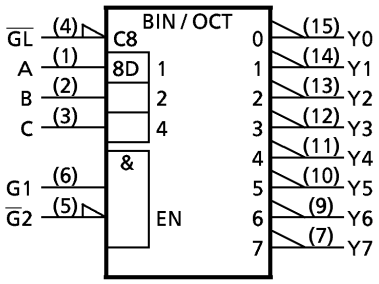
F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)

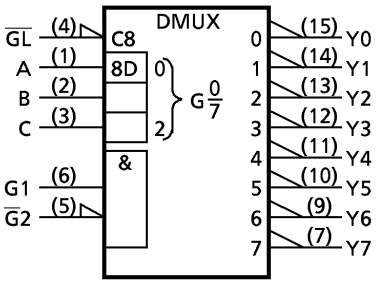
PIN ASSIGNMENT



(TOP VIEW)

IEC LOGIC SYMBOL





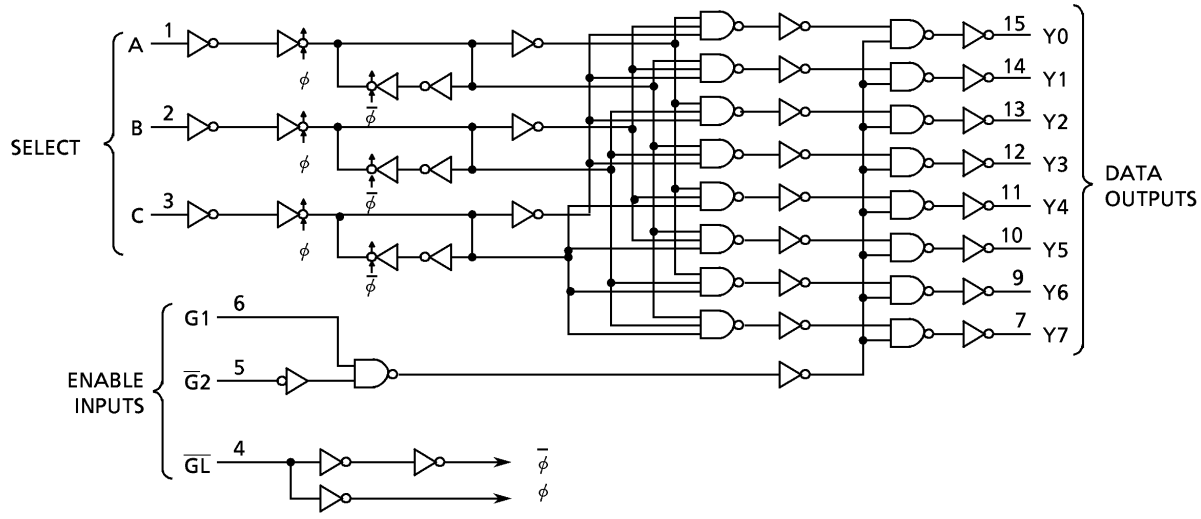
961001EBA2

TRUTH TABLE

INPUTS						OUTPUTS							
ENABLE			ADDRESS			Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
$\overline{GL}$	$\overline{G2}$	G1	C	B	A								
X	X	L	X	X	X	L	L	L	L	L	L	L	L
X	H	X	X	X	X	L	L	L	L	L	L	L	L
L	L	H	L	L	L	H	L	L	L	L	L	L	L
L	L	H	L	L	H	L	H	L	L	L	L	L	L
L	L	H	L	H	L	L	L	H	L	L	L	L	L
L	L	H	L	H	H	L	L	L	H	L	L	L	L
L	L	H	H	L	L	L	L	L	L	H	L	L	L
L	L	H	H	L	H	L	L	L	L	L	H	L	L
L	L	H	H	H	L	L	L	L	L	L	L	H	L
L	L	H	H	H	H	L	L	L	L	L	L	L	H
H	L	H	X	X	X	Depends upon the address previously applied while $\overline{GL}$ was at a low level							

X : Don't care

SYSTEM DIAGRAM



961001EBA2'

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7	V
DC Input Voltage	V_{IN}	−0.5~V_{CC}+0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC}+0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	−65~150	°C

*500mW in the range of Ta= −40°C~65°C. From Ta=65°C to 85 °C a derating factor of −10mW/°C shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 (V_{CC}=2.0V) 0~ 500 (V_{CC}=4.5V) 0~ 400 (V_{CC}=6.0V)	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta=25°C MIN.	Ta=25°C TYP.	Ta=25°C MAX.	Ta=−40~85°C MIN.	Ta=−40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low - Level Input Voltage	V_{IL}			2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High - Level Output Voltage	V_{OH}	V_{IN}= V_{IH} or V_{IL}	I_{OH}=−20μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	— — —	1.9 4.4 5.9	— — —	V
			I_{OH}=−4 mA I_{OH}=−5.2mA	4.5 6.0	4.18 5.68	4.31 5.80	— —	4.13 5.63	— —	
Low - Level Output Voltage	V_{OL}	V_{IN}= V_{IH} or V_{IL}	I_{OL}=20μA	2.0 4.5 6.0	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			I_{OL}=4 mA I_{OL}=5.2mA	4.5 6.0	— —	0.17 0.18	0.26 0.26	— —	0.33 0.33	
Input Leakage Current	I_{IN}	V_{IN}=V_{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN}=V_{CC} or GND		6.0	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C TYP.	Ta = 25°C LIMIT	Ta = −40~85°C LIMIT	UNIT
Minimum Pulse Width ($\overline{GL}$)	$t_{W(L)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Set−up Time (A, B, C−$\overline{GL}$)	t_s		2.0	—	50	65	
			4.5	—	10	13	
			6.0	—	9	11	
Minimum Hold Time (A, B, C−$\overline{GL}$)	t_h		2.0	—	25	30	
			4.5	—	5	6	
			6.0	—	5	5	

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	4	8	ns
Propagation Delay Time (G1−Y)	t_{pLH} t_{pHL}		—	12	24	
Propagation Delay Time ($\overline{G}$2−Y)	t_{pLH} t_{pHL}		—	12	24	
Propagation Delay Time ($\overline{GL}$−Y)	t_{pLH} t_{pHL}		—	17	33	
Propagation Delay Time (A, B, C−Y)	t_{pLH} t_{pHL}		—	15	31	

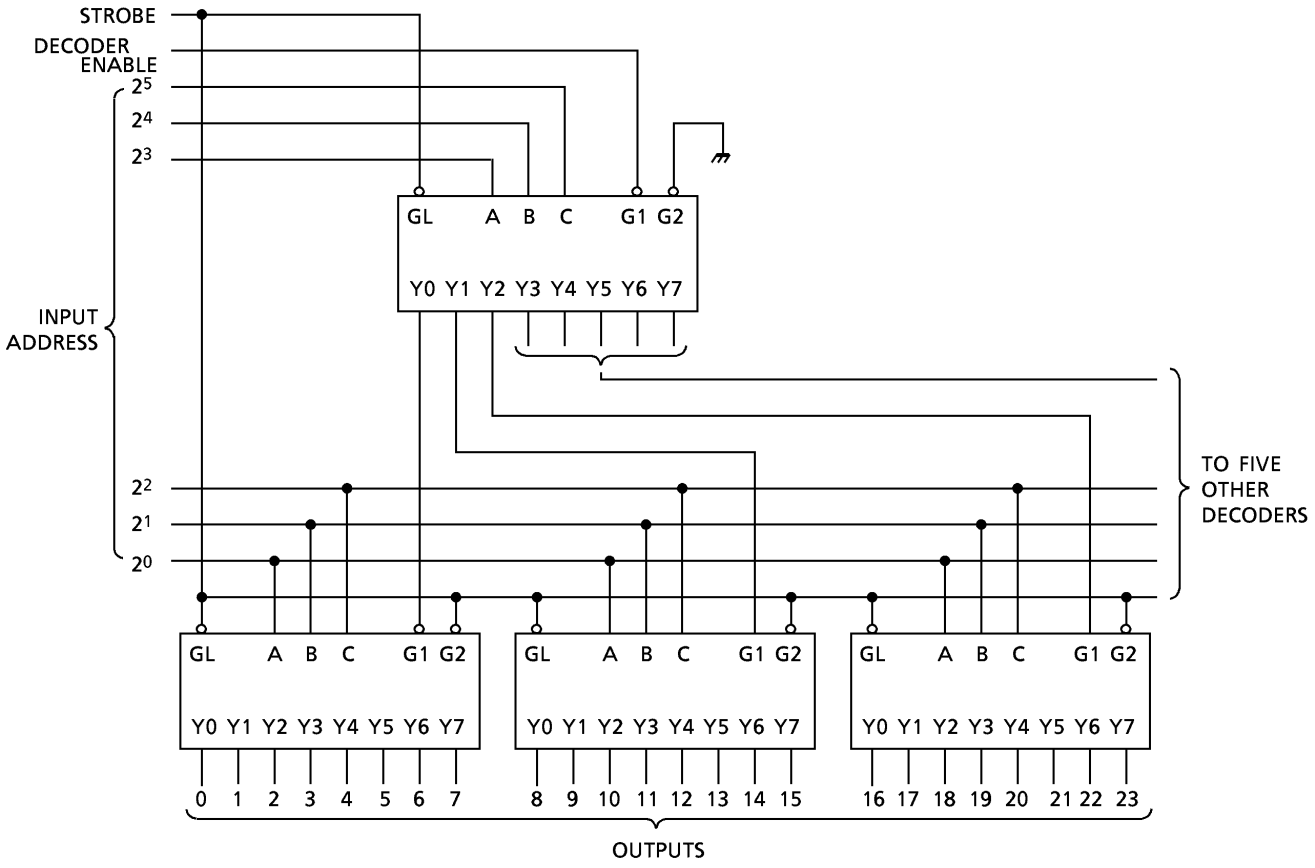
AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (G1−Y)	t_{pLH} t_{pHL}		2.0	—	45	140	—	175	
			4.5	—	15	28	—	35	
			6.0	—	13	24	—	30	
Propagation Delay Time ($\overline{G}$2−Y)	t_{pLH} t_{pHL}		2.0	—	45	140	—	175	
			4.5	—	15	28	—	35	
			6.0	—	13	24	—	30	
Propagation Delay Time ($\overline{GL}$−Y)	t_{pLH} t_{pHL}		2.0	—	65	190	—	240	
			4.5	—	21	38	—	48	
			6.0	—	18	32	—	41	
Propagation Delay Time (A, B, C−Y)	t_{pLH} t_{pHL}		2.0	—	60	180	—	225	
			4.5	—	19	36	—	45	
			6.0	—	16	31	—	38	
Input Capacitance	C_{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD} (1)			—	52	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

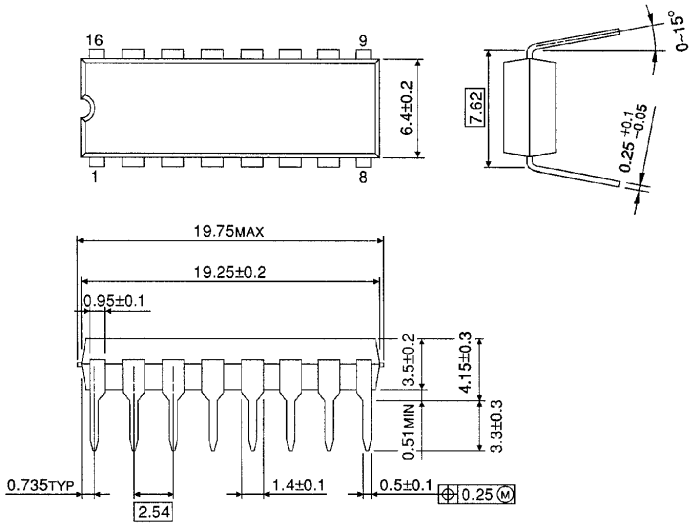
$$I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

TYPICAL APPLICATION



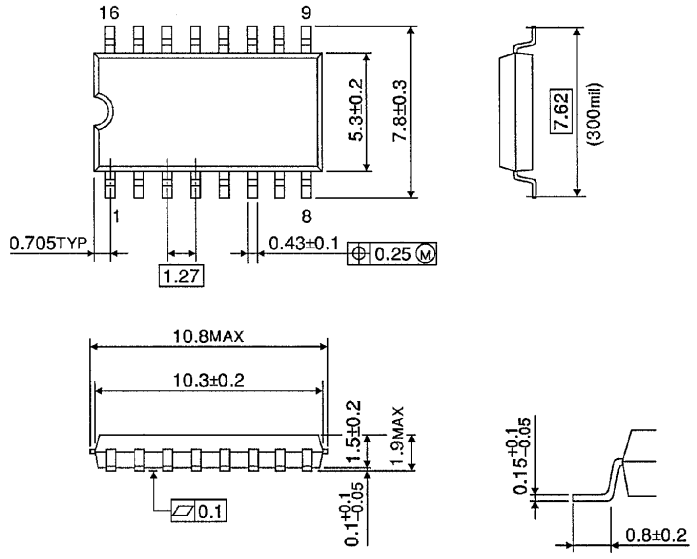
6 Line to 64 Line Decoder with Input Address Storage

DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A) Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27) Unit in mm



Weight : 0.18g (Typ.)